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AMENDMENTS TO THE CLAIMS

This listing of claims will replace all prior versions and listings of claims in the

application:

LISTING OF CLAIMS:

Claims 1-28. (canceled).

(previously presented): A hydrogen gas sensor comprising;

a proton-conductive layer formed of a polymer electrolyte;

first and second electrodes provided in contact with the proton-conductive layer:

a diffusion-rate limiting portion disposed between the first electrode and an atmosphere

of a gas under measurement containing hydrogen; and

a circuit for applying a voltage between the first and second electrodes such that

hydrogen introduced from the atmosphere via the diffusion-rate limiting portion undergoes

dissociation, decomposition, or reaction to produce protons on the first electrode, and for

determining the hydrogen concentration of the gas under measurement based on a saturation

current which flows as a result of conduction of protons from the first electrode to the second

electrode via the proton-conductive layer;

said sensor having a proton-conducting rate from the first electrode to the second

electrode that is greater than a rate at which protons derived from hydrogen are introduced onto

the first electrode via the diffusion-rate limiting portion, and

wherein the gas-diffusion resistance of the diffusion-rate limiting portion is set such that

current (a) > current (b):

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current (a) is a current flowing between the first and second electrodes upon application of a voltage of 50 mV or higher between the first and second electrodes in a state in which the gas-diffusion resistance of the diffusion-rate limiting portion is 0.9 mA/mm<sup>2</sup> or more with current conversion at  $H_2 = 40\%$  and the measurement gas has a  $H_2$ O concentration of 10% or less at 80°C or a CO concentration of 1,000 ppm or greater; and

current (b) is a saturation current flowing between the first and second electrodes in a state in which the gas-diffusion resistance of the diffusion-rate limiting portion is less than 0.9  $mA/mm^2$  with current conversion at  $H_2 = 40\%$  and the measurement gas has a  $H_2O$  concentration of 15% or greater at 80°C or a CO concentration of 800 ppm or less.

(previously presented): A hydrogen gas sensor comprising:
a proton-conductive layer formed of a polymer electrolyte;

first and second electrodes and a reference electrode provided in contact with the protonconductive layer;

a diffusion-rate limiting portion disposed between the first electrode and an atmosphere of a gas under measurement containing hydrogen; and

a circuit for applying a voltage between the first and second electrodes such that a constant voltage develops between the first electrode and the reference electrode, and such that hydrogen gas introduced from the atmosphere via the diffusion-rate limiting portion undergoes dissociation, decomposition, or reaction to produce portions on the first or second electrode, and for detecting the hydrogen concentration of the gas under measurement based on a saturation current which flows as a result of conduction of protons via the proton-conductive layer; wherein

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said sensor having a proton conducting rate from the first electrode to the second electrode that is greater than a rate at which protons derived from hydrogen are introduced onto the first electrode via the diffusion-rate limiting portion, and

wherein the gas-diffusion resistance of the diffusion-rate limiting portion is set such that current (a) > current (b):

current (a) is a current flowing between the first and second electrodes upon application of a voltage of 50 mV or higher between the first and second electrodes in a state in which the gas-diffusion resistance of the diffusion-rate limiting portion is 0.9 mA/mm<sup>2</sup> or more with current conversion at  $H_2 = 40\%$  and the measurement gas has a  $H_2$ O concentration of 10% or less at 80°C or a CO concentration of 1,000 ppm or greater;

current (b) is a saturation current flowing between the first and second electrodes in a state in which the gas-diffusion resistance of the diffusion-rate limiting portion is less than 0.9  $mA/mm^2$  with current conversion at  $H_2 = 40\%$  and the measurement gas has a  $H_2O$  concentration of 15% or greater at 80°C or a CO concentration of 800 ppm or less.

- (new): The hydrogen gas sensor as claimed in claim 29, wherein the diffusionrate limiting portion comprises a dense body having a through-hole having an opening diameter of 1 µm or higher.
- 32. (new): The hydrogen gas sensor as claimed in claim 30, wherein the diffusionrate limiting portion comprises a dense body having a through-hole having an opening diameter of 1 um or higher.

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33. (new): The hydrogen gas sensor as claimed in claim 31, wherein the opening diameter of the through-hole is 30  $\mu m$  or higher.

- (new): The hydrogen gas sensor as claimed in claim 32, wherein the opening diameter of the through-hole is 30 µm or higher.
- 35. (new): The hydrogen gas sensor as claimed in claim 31, wherein the opening diameter of the through-hole is 1 µm or higher and 70 µm or lower.
- 36. (new): The hydrogen gas sensor as claimed in claim 32, wherein the opening diameter of the through-hole is 1 μm or higher and 70 μm or lower.